

Description

The SXG130N10NF uses advanced technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

$V_{DS} = 100V$ $I_D = 130A$

$R_{DS(ON)} < 4.2m\Omega$ @ $V_{GS}=10V$

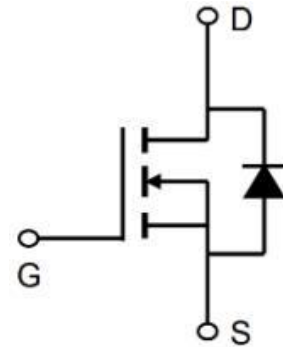
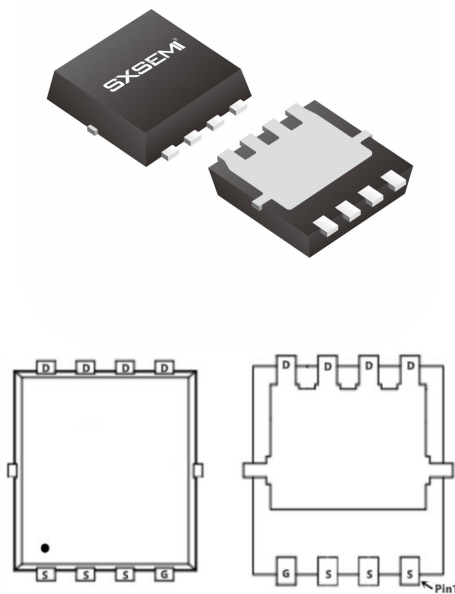
Application

Isolated DC

Motor control

Synchronous-rectification

PDFN5*6-8L



Absolute Maximum Ratings ($T_c=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Rating	Units
VDS	Drain-Source Voltage	100	V
VGS	Gate-Source Voltage	± 20	V
$I_D@T_A=25^\circ C$	Continuous Drain Current ¹	130	A
$I_D@T_A=70^\circ C$	Continuous Drain Current ¹	78	A
IDM	Pulsed Drain Current ²	480	A
EAS	Single Pulse Avalanche Energy ³	320	mJ
IAS	Avalanche Current	40	A
$P_D@T_A=25^\circ C$	Total Power Dissipation ⁴	131.6	W
TSTG	Storage Temperature Range	-55 to 150	$^\circ C$
TJ	Operating Junction Temperature Range	-55 to 150	$^\circ C$
R θ JA	Thermal Resistance Junction-Ambient ¹	25	$^\circ C/W$
R θ JC	Thermal Resistance Junction-Case ¹	0.95	$^\circ C/W$

Electrical Characteristics (T_C=25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V(BR)DSS	Drain-Source Breakdown Voltage	V _{GS} = 0V, I _D = 250μA	100	107	-	V
IGSS	Gate-body Leakage current	V _{DS} = 0V, V _{GS} = ±20V	-	-	±100	nA
IDSS	Zero Gate Voltage Drain Current T _J =25°C	V _{DS} = 100V, V _{GS} = 0V	-	-	1	μA
	Zero Gate Voltage Drain Current T _J =100°C		-	-	100	
VGS(th)	Gate-Threshold Voltage	V _{DS} = V _{GS} , I _D = 250μA	1.2	1.8	2.5	V
RDS(on)	Drain-Source on-Resistance ⁴	V _{GS} = 10V, I _D = 20A	-	3.2	4.5	mΩ
		V _{GS} = 4.5V, I _D = 15A	-	5.2	6.7	
gfs	Forward Transconductance ⁴	V _{DS} = 10V, I _D = 20A	-	70	-	S
Ciss	Input Capacitance	V _{DS} = 50V, V _{GS} = 0V, f = 1MHz	-	5475	-	pF
Coss	Output Capacitance		-	768	-	
Crss	Reverse Transfer Capacitance		-	22	-	
R _g	Gate Resistance	f = 1MHz	-	1.3	-	Ω
Q _g	Total Gate Charge	V _{GS} = 10V, V _{DS} = 50V, I _D = 20A	-	111.2	-	nC
Q _{gs}	Gate-Source Charge		-	17.5	-	
Q _{gd}	Gate-Drain Charge		-	30.2	-	
td(on)	Turn-on Delay Time	V _{GS} = 10V, V _{DD} = 50V, R _G = 3Ω, I _D = 20A	-	22.2	-	ns
t _r	Rise Time		-	37.8	-	
td(off)	Turn-off Delay Time		-	95.2	-	
t _f	Fall Time		-	35.6	-	
trr	Body Diode Reverse Recovery Time	I _F = 20A, dI/dt = 100A/μs	-	59.4	-	ns
Q _{rr}	Body Diode Reverse Recovery Charge		-	91.8	-	nC
VSD	Diode Forward Voltage ⁴	I _S = 20A, V _{GS} = 0V	-	-	1.2	V
IS	Continuous Source Current T _C =25°C	-	-	-	120	A

Note :

- 1、The data tested by surface mounted on a 1 inch 2 FR-4 board with 2OZ copper.
- 2、The data tested by pulsed , pulse width ≤ 300us , duty cycle ≤ 2%
- 3、The EAS data shows Max. rating . The test condition is VDD=72V,VGS=10V, L=0.1mH IAS=40A
- 4、The power dissipation is limited by 150°C junction temperature
- 5、The data is theoretically the same as I_D and I_{DM} , in real applications , should be limited by total power dissipation

Typical Characteristics

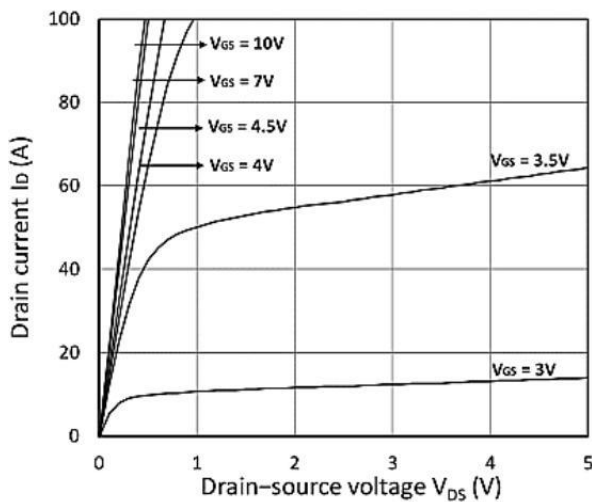


Figure 1. Output Characteristics

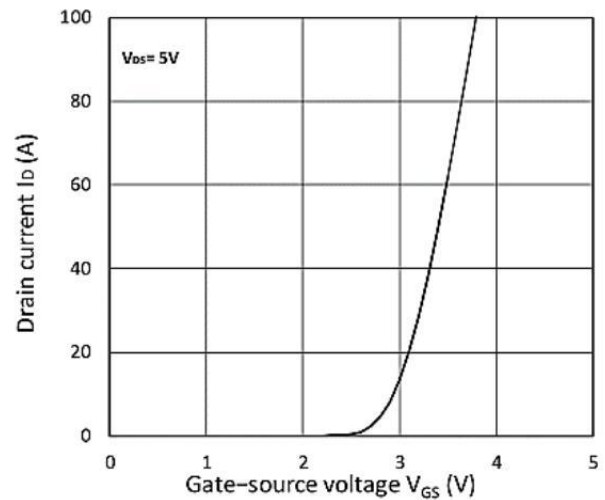


Figure 2. Transfer Characteristics

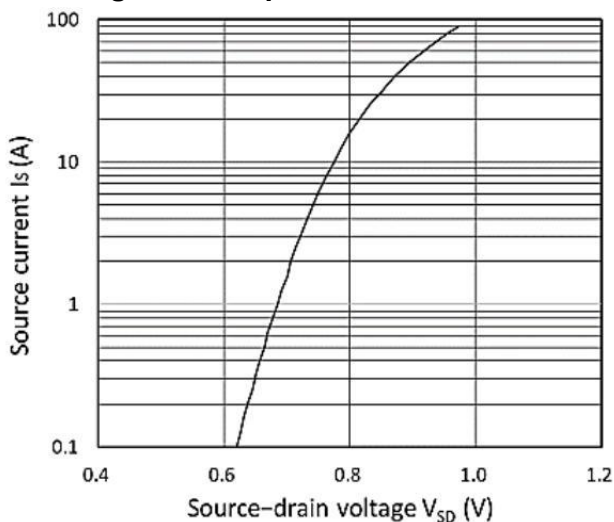


Figure 3. Forward Characteristics of Reverse

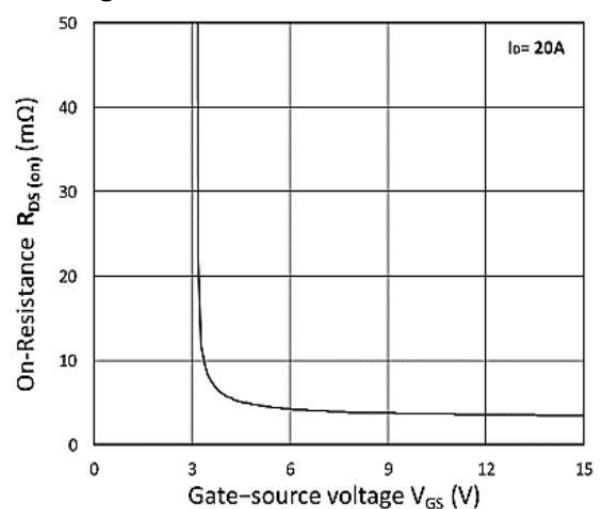


Figure 4. R_DS(ON) vs. V_GS

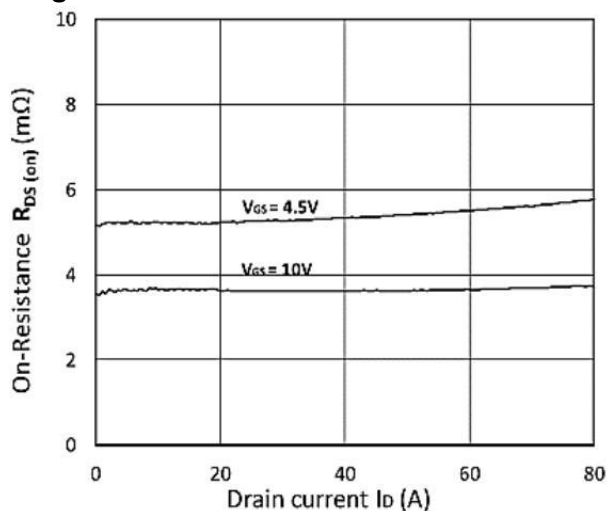


Figure 5. R_DS(ON) vs. I_D

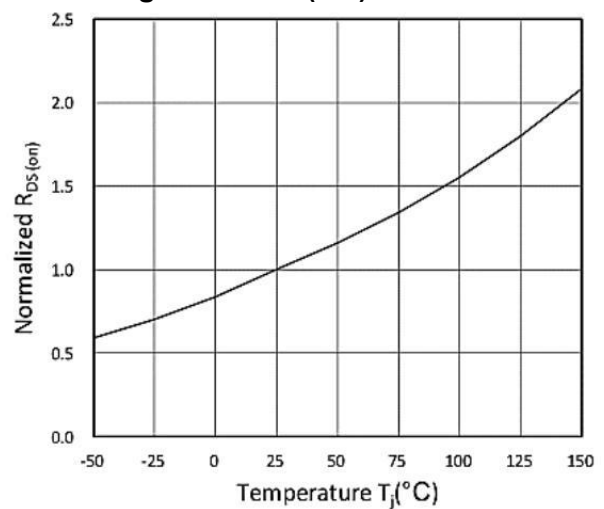


Figure 6. Normalized R_DS(on) vs. Temperature

Typical Characteristics

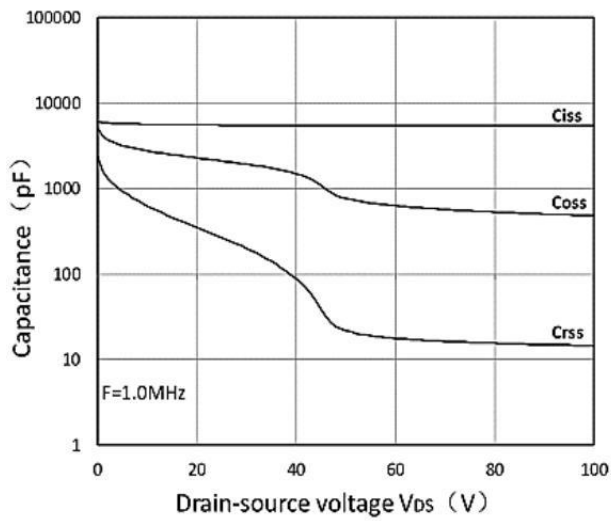


Figure 7. Capacitance Characteristics

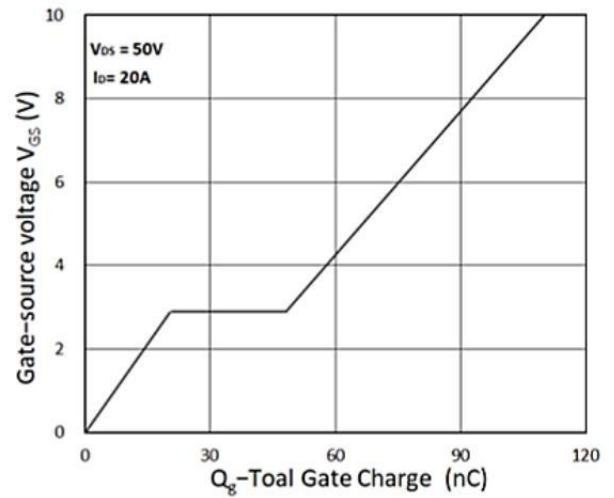


Figure 8. Gate Charge Characteristics

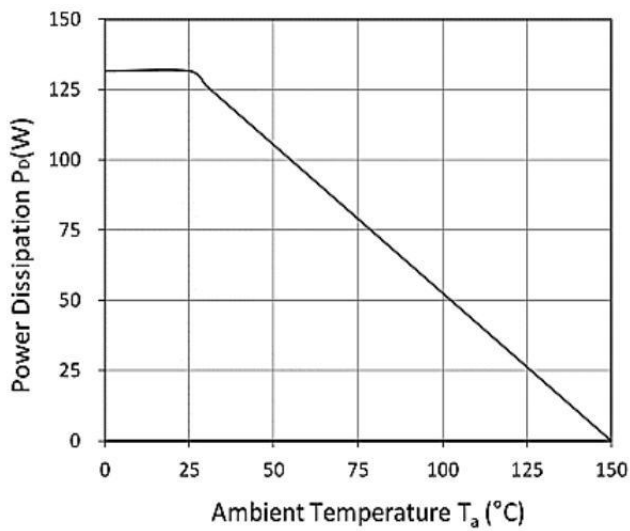


Figure 9. Power Dissipation

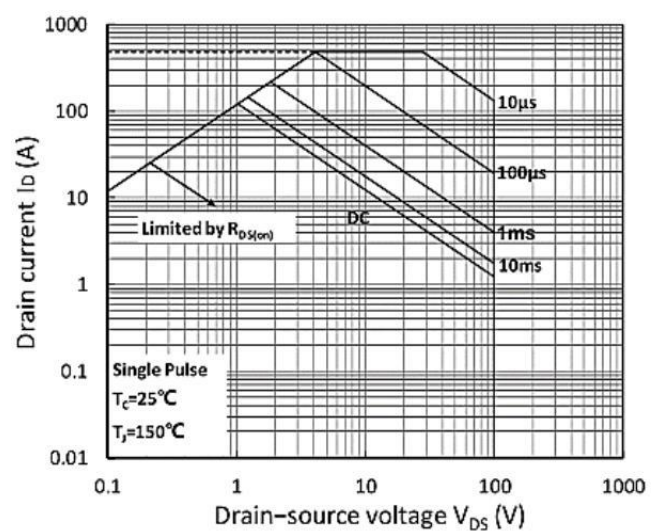


Figure 10. Safe Operating Area

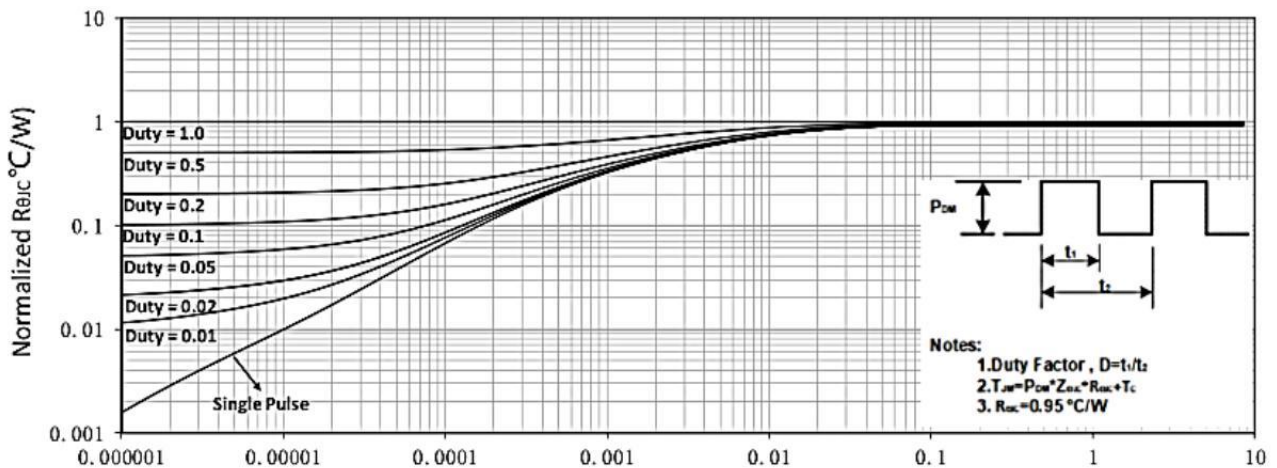
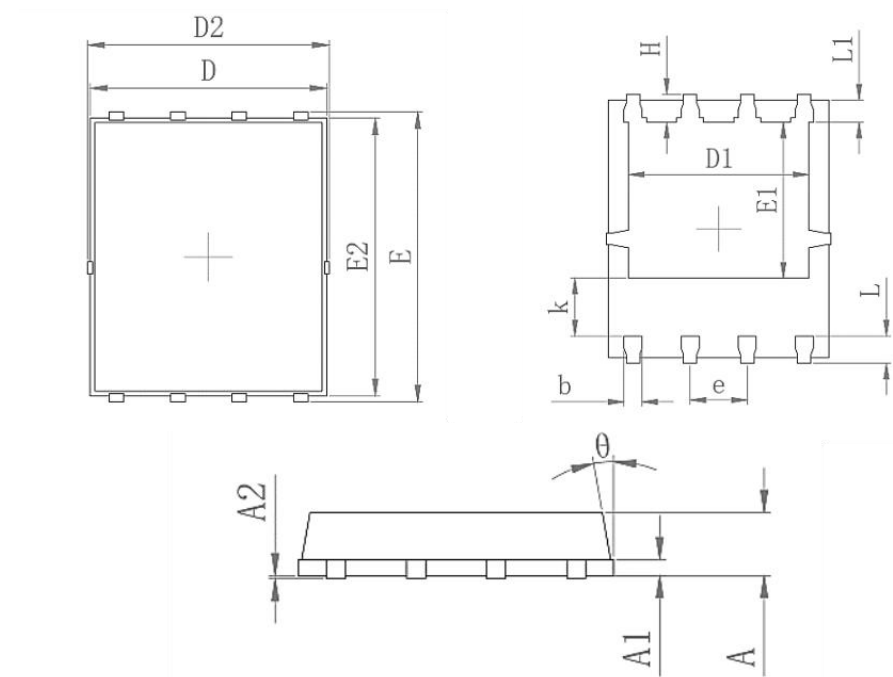


Figure 11. Normalized Maximum Transient Thermal Impedance

Package Mechanical Data-PDFN5X6-8L-XZT Single


Symbol	Common	
	mm	
	Mim	Max
A	0.90	1.10
A1	0.254 REF	
A2	0-0.05	
D	4.824	4.976
D1	3.910	4.110
D2	4.944	5.076
E	5.924	6.076
E1	3.375	3.575
E2	5.674	5.826
b	0.350	0.450
e	1.270	
L	0.534	0.686
L1	0.424	0.576
K	1.190	1.390
H	0.549	0.701
Φ	8°	12°

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
TAPING	PDFN5*6-8L		5000